

High-speed USB OTG ESD protection diode arrays Rev. 3 — 14 June 2012 Produce

Product data sheet

#### **Product profile** 1.

### 1.1 General description

PUSBMxX4-TL is a series of four 4-channel ElectroStatic Discharge (ESD) diode arrays for USB 2.0 (On-The-Go (OTG)) interfaces. The devices provide protection to downstream components from ESD voltages up to ±8 kV contact discharge. They offer three low capacitance ESD protection pins and one V<sub>BUS</sub> protection diode. They are encapsulated in an ultra thin DFN1616-6 (SOT1189-1/XSON6) plastic package with 0.5 mm pitch. These features make the devices ideal for use in applications requiring component miniaturization, such as mobile phone handsets.

### 1.2 Features and benefits

- Pb-free, Restriction of Hazardous Substances (RoHS) and Dark Green compliant
- ESD protection according to IEC 61000-4-2 level 4: ±8 kV contact discharge
- Electrical Fast Transients (EFT) protection according to IEC 61000-4-4 40A (5/50 ns)
- Three pairs of ultra low capacitance (1.1 pF typ.) rail-to-rail ESD protection diodes
- Ultra thin DFN1616-6 (SOT1189-1/XSON6) plastic package; 0.5 mm pitch

### 1.3 Applications

High-speed USB 2.0 and USB OTG connector ESD protection in:

- Cellular phone and Personal Communication System (PCS) mobile handsets
- Mobile internet devices
- Digital still cameras
- Portable media players

#### **Pinning information** 2.

Table 1.	Pinning		
Pin	Description	Simplified outline	Graphic symbol
1	low capacitance ESD protection		
2	low capacitance ESD protection	6 5 4	
3	low capacitance ESD protection		$\begin{array}{cccccccccccccccccccccccccccccccccccc$
4	not connected	7	$\uparrow$ $\downarrow$ $\downarrow$ $\downarrow$ $\downarrow$ $\downarrow$ $\downarrow$
5	not connected		
6	V <sub>BUS</sub> ESD protection	1 2 3	¢center pad
7	ground (GND)	Transparent top view	018aaa140



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## 3. Ordering information

Type number	Package		
	Name	Description	Version
PUSBM5V5X4-TL	DFN1616-6	plastic, thermal enhanced extremely thin small outline package; no leads; 6 terminals; body $1.6 \times 1.6 \times 0.5$ mm	SOT1189-1
PUSBM12VX4-TL			
PUSBM15VX4-TL			
PUSBM30VX4-TL			

## 4. Marking

Table 3.   Marking codes	
Type number	Marking code
PUSBM5V5X4-TL	XE
PUSBM12VX4-TL	XL
PUSBM15VX4-TL	XO
PUSBM30VX4-TL	30

## 5. Limiting values

#### Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>RWM</sub>	reverse standoff voltage	pins 1, 2, 3	-0.5	+5.5	V
	PUSBM5V5X4-TL	pin 6 (V <sub>BUS</sub> )	-0.5	+5.5	V
	PUSBM12VX4-TL	pin 6 (V <sub>BUS</sub> )	-0.5	+12	V
	PUSBM15VX4-TL	pin 6 (V <sub>BUS</sub> )	-0.5	+15	V
	PUSBM30VX4-TL	pin 6 (V <sub>BUS</sub> )	-0.5	+30	V
V <sub>ESD</sub>	electrostatic discharge voltage	IEC 61000-4-2, level 4; pins 1, 2, 3, 6 to GND; contact discharge	[1] -	±8	kV
P <sub>PP</sub>	peak pulse power	$t_p = 8/20 \ \mu s$			
		pins 1, 2, 3; V <sub>CL</sub> = 12 V	-	35	W
	PUSBM5V5X4-TL	pin 6 (V <sub>BUS</sub> ); V <sub>CL</sub> = 9.2 V	-	100	W
	PUSBM12VX4-TL	pin 6 (V <sub>BUS</sub> ); V <sub>CL</sub> = 16 V	-	100	W
	PUSBM15VX4-TL	pin 6 (V <sub>BUS</sub> ); V <sub>CL</sub> = 22 V	-	100	W
	PUSBM30VX4-TL	pin 6 (V <sub>BUS</sub> ); V <sub>CL</sub> = 43 V	-	100	W
I <sub>PP</sub>	peak pulse current	$t_p = 8/20 \ \mu s$			
		pins 1, 2, 3	-	3	А
	PUSBM5V5X4-TL	pin 6 (V <sub>BUS</sub> )	-	12	А
	PUSBM12VX4-TL	pin 6 (V <sub>BUS</sub> )	-	6	А
	PUSBM15VX4-TL	pin 6 (V <sub>BUS</sub> )	-	3	А
	PUSBM30VX4-TL	pin 6 (V <sub>BUS</sub> )	-	2	А

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#### Table 4. Limiting values ...continued

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
T <sub>reflow(peak)</sub>	peak reflow temperature	$t_p \le 10 \text{ s}$	-	+260	°C
T <sub>amb</sub>	ambient temperature		-30	+85	°C
T <sub>stg</sub>	storage temperature		-55	+150	°C

[1] Device is qualified with 1000 pulses of ±8 kV contact discharges each, according to IEC61000-4-2 far exceeding level 4 (±8 kV contact discharge).

## 6. Characteristics

#### Table 5.Characteristics

 $T_{amb} = 25 \ ^{\circ}C$  unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V <sub>F</sub>	forward voltage		0.6	-	1.2	V
Low capaci	tance ESD protection					
V <sub>BRzd</sub>	Zener diode breakdown voltage	I <sub>test</sub> = 1 mA	6	-	10	V
C <sub>(I/O-GND)</sub>	input/output to ground capacitance	V <sub>bias(DC)</sub> = 0.5 V; f = 1 MHz; pins 1, 2, 3 to GND	<u>[1]</u> -	1.1	1.3	pF
$\Delta C_{(I/O-GND)}$	input/output to ground capacitance variation	$V_{bias(DC)} = 0.5 V$ ; f = 1 MHz	-	0.02	-	pF
C <sub>(I/O-I/O)</sub>	input/output to input/output capacitance	V <sub>bias(DC)</sub> = 0.5 V; f = 1 MHz; pins 1 to 2, 1 to 3, 2 to 3	-	0.5	-	pF
I <sub>RM</sub>	reverse leakage current	pins 1, 2, 3 to GND; $V_{RWM}$ = 5.5 V	-	100	1000	nA
V <sub>BUS</sub> ESD p	rotection					
V <sub>BR</sub>	breakdown voltage	pin 6 (V <sub>BUS</sub> ) to GND; $I_{test} = 1 \text{ mA}$				
	PUSBM5V5X4-TL		6.4	6.8	7.2	V
	PUSBM12VX4-TL		12.5	14.5	16	V
	PUSBM15VX4-TL		17	18	19	V
	PUSBM30VX4-TL		32	36	40	V
C <sub>d</sub>	diode capacitance	$V_{bias(DC)} = 0.5 V$ ; f = 1 MHz; pin 6 (V <sub>BUS</sub> ) to GND				
	PUSBM5V5X4-TL		-	165	220	pF
	PUSBM12VX4-TL		-	73	100	pF
	PUSBM15VX4-TL		-	60	90	pF
	PUSBM30VX4-TL		-	50	70	pF
I <sub>RM</sub>	reverse leakage current	pin 6 (V <sub>BUS</sub> ) to GND				
	PUSBM5V5X4-TL	V <sub>RWM</sub> = 5.5 V	-	200	500	nA
	PUSBM12VX4-TL	$V_{RWM} = 12 V$	-	1	100	nA
	PUSBM15VX4-TL	$V_{RWM} = 15 V$	-	1	100	nA
	PUSBM30VX4-TL	$V_{RWM} = 30 V$	-	1	100	nA

[1] Guaranteed by design.

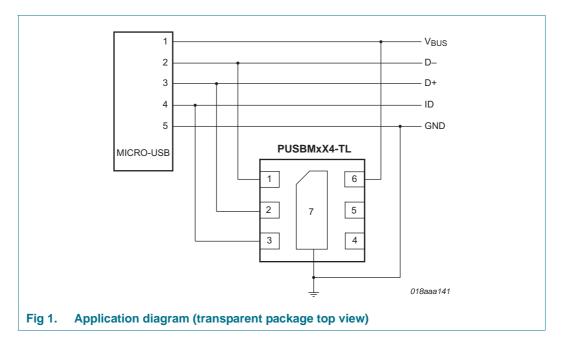
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## 7. Application information

### 7.1 Typical application

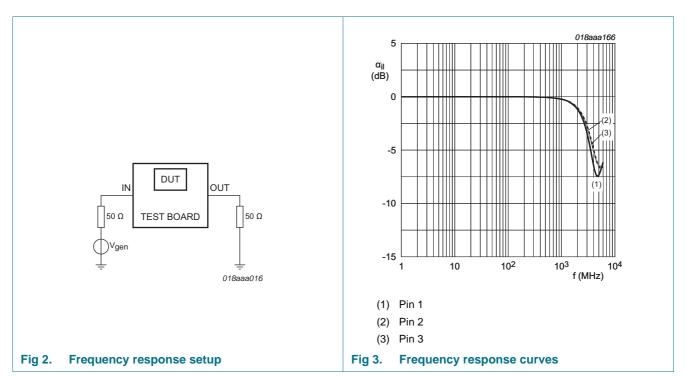
The devices are designed to protect USB interfaces from downstream ESD. They offer three low capacitance ESD protection channels for D–, D+ and ID and a high-voltage ESD protection channel for  $V_{BUS}$ .



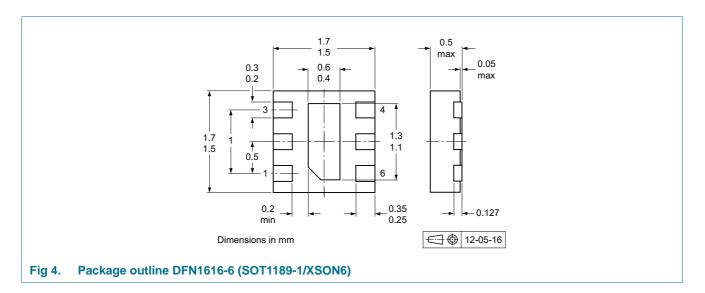
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### 7.2 Insertion loss

The setup for measuring frequency response curves in a 50  $\Omega$  system is shown in Figure 2. The frequency response curves for the low capacitance ESD protection channels (pins 1 to 3) are depicted in Figure 3.



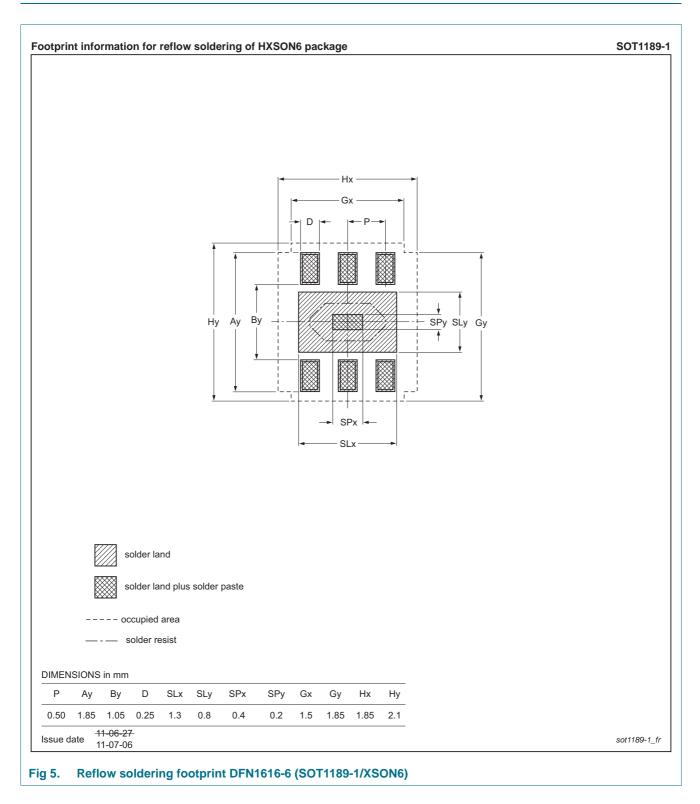
## 8. Package outline



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## 9. Soldering



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## **10. Revision history**

Table 6. Revision histo	ory			
Document ID	Release date	Data sheet status	Change notice	Supersedes
PUSBMXX4-TL_SER v.3	20120614	Product data sheet	-	PUSBMXX4-TL_SER v.2
Modifications:	• Figure 1 update	i <mark>ing information"</mark> : simplified ed ed by minimized package o		d
PUSBMXX4-TL_SER v.2	20120416	Preliminary data sheet	-	PUSBMXX4-TL_SER v.1
PUSBMXX4-TL_SER v.1	20111209	Preliminary data sheet	-	-

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## **11. Legal information**

### 11.1 Data sheet status

Document status[1][2]	Product status <sup>[3]</sup>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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